



A Product Line of **Diodes Incorporated** 



### Features

- BV<sub>CEO</sub> > 75V
- I<sub>c</sub> = 3A high Continuous Current
- I<sub>CM</sub> = 10A Peak Pulse Current
- High Gain Holds up h<sub>FE</sub> > 300 @ I<sub>C</sub>=1A
- Low Equivalent On-Resistance; R<sub>CE(sat)</sub> = 78mΩ at 4.5A
- Excellent hFE characteristics up to 10A
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

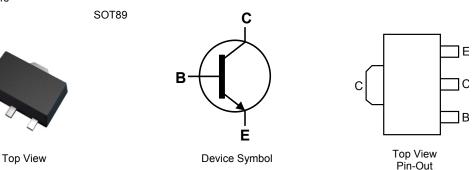
# Applications

- **Emergency Lighting Circuits**
- Motor Driving (including DC fans)
- Solenoid, Relay and Actuator Drivers
- DC DC Modules
- Backlight Inverters
- **Power Switches**
- **MOSFET Gate Drivers**



### Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.052 grams (Approximate)



### Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FCX1053ATA	053	7	12	1,000
FCX1053A-13R	053	13	12	4,000

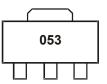
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

Notes:

and Lead-free 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



053 = Product Type Marking Code





#### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	150	V
Collector-Emitter Voltage	V <sub>CEO</sub>	75	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	3	А
Base Current	IB	500	mA
Peak Pulse Current	I <sub>CM</sub>	10	А

#### **Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		1		
Power Dissipation	(Note 6)	PD	1.6	W	
	(Note 7)		2.0		
	(Note 5)		125		
Thermal Resistance, Junction to Ambient Air	(Note 6)	R <sub>0JA</sub>	78	°C/W	
	(Note 7)		62.5		
Thermal Resistance, Junction to Lead	(Note 8)	$R_{\theta JL}$	3.6	°C/W	
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C		

#### ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

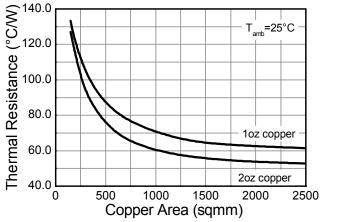
6. Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.

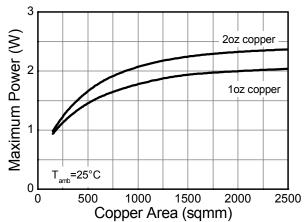
7. Same as note (5), except the device is mounted on 50mm x 50mm 1oz copper.

8. Thermal resistance from junction to solder-point (on the exposed collector pad).

9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

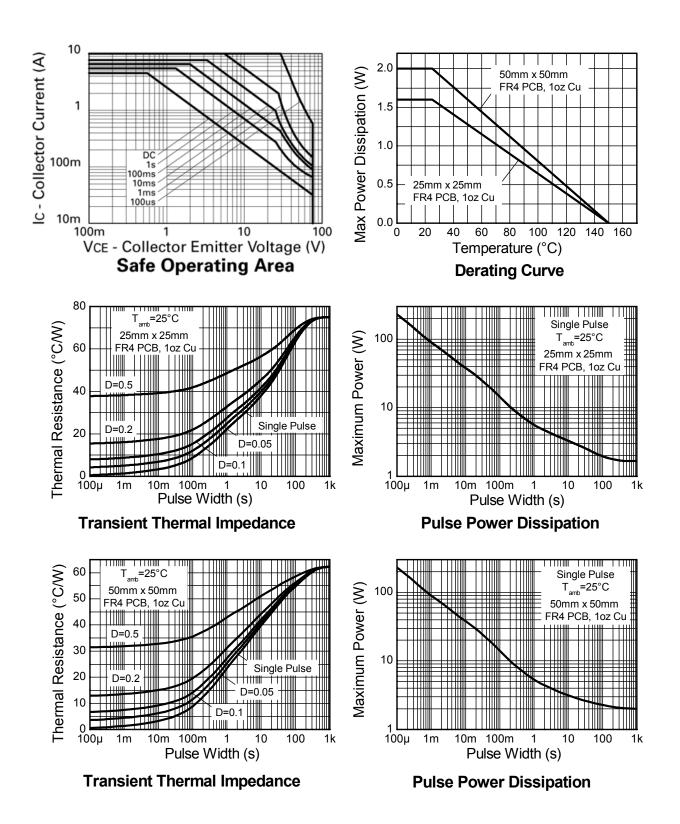
## Thermal Characteristics and Derating Information













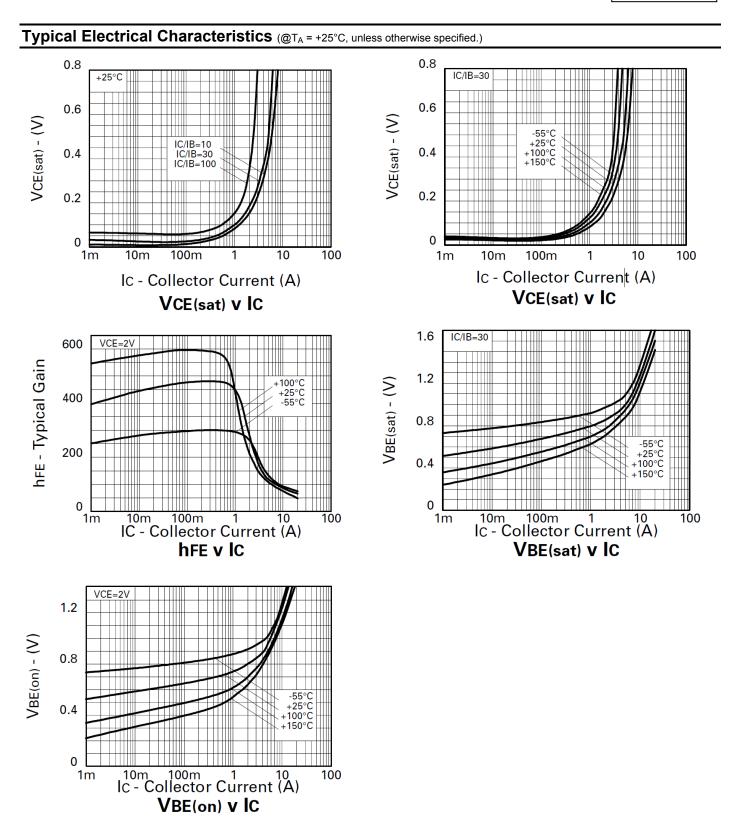


Electrical Characteristics (@T <sub>A</sub> = +25°C, unless otherwise specified.)						
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	150	250	—	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>	150	250	—	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Notes 10)	BV <sub>CEO</sub>	75	100	—	V	I <sub>C</sub> = 10mA
Collector-Emitter Breakdown Voltage	BVCEV	150	250	—	V	I <sub>C</sub> = 100μA, V <sub>EB</sub> = 1V
Emitter-Base Breakdown Voltage	BVEBO	7	8.8	_	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	Ісво	_	0.9	50	nA	V <sub>CB</sub> = 120V
Collector Cutoff Current	I <sub>CES</sub>	_	1.5	50	nA	V <sub>CES</sub> = 120V
Emitter Cutoff Current	I <sub>EBO</sub>	—	0.3	20	nA	V <sub>EB</sub> = 5.6V
DC current transfer Static ratio (Notes 10)	h <sub>FE</sub>	270 300 300 40	440 450 450 60 20	1200		$\begin{split} I_{C} &= 10 \text{mA}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 0.5 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 1 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 4.5 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 10 \text{A}, \ V_{CE} = 2 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Notes 10)	V <sub>CE(sat)</sub>	_	21 55 150 160 350	30 75 200 210 440	mV	$\begin{split} I_{C} &= 0.2A, \ I_{B} = 20mA \\ I_{C} &= 0.5A, \ I_{B} = 20mA \\ I_{C} &= 1A, \ I_{B} = 10mA \\ I_{C} &= 2A, \ I_{B} = 100mA \\ I_{C} &= 4.5A, \ I_{B} = 200mA \end{split}$
Base-Emitter Saturation Voltage (Notes 10)	V <sub>BE(sat)</sub>	—	900	1000	mV	I <sub>C</sub> = 3A, I <sub>B</sub> = 100mA
Base-Emitter Turn-on Voltage (Notes 10)	V <sub>BE(on)</sub>	—	825	950	mV	$I_{C}$ = 3A, $V_{CE}$ = 2V
Transitional Frequency	f⊤	_	140	_	MHz	I <sub>C</sub> = 50mA, V <sub>CE</sub> = 10V, f = 100MHz
Output capacitance	C <sub>obo</sub>	_	21	30	pF	V <sub>CB</sub> = 10V, f = 1MHz,
Switching Time	t <sub>on</sub>		162		ns	V <sub>CC</sub> = 50V, I <sub>C</sub> = 2A,
Switching Time	t <sub>off</sub>	] —	900		ns	$I_{B1} = I_{B2} = \pm 20 \text{mA}$

Note: 10. Measured under pulsed conditions. Pulse width =  $300\mu$ s. Duty cycle  $\leq 2\%$ .





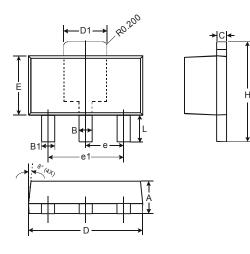






### **Package Outline Dimensions**

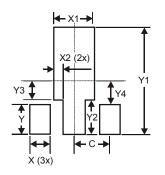
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min Max			
Α	1.40 1.60			
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.43		
D	4.40 4.60			
D1	1.52	1.83		
ш	2.29 2.60			
е	e 1.50 Typ			
e1	3.00 Typ			
Н	3.94 4.25			
L	0.89 1.20			
All Dimensions in mm				

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500





#### IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

- 1. are intended to implant into the body, or
- 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2014, Diodes Incorporated

www.diodes.com